Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

1.125 inches

# **Overall Diameter:**

1.062 inches

# **Mounting Facility Quantity:**

1

### **Mounting Method:**

Threaded stud

**Features Provided:** 

Hermetically sealed case

Thread Size:

0.500 inches

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

10.0 peak negative gate voltage

### **Current Rating Per Characteristic:**

2.00 amperes source cutoff current minor

# Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

# **Thread Series Designator:**

Unf

# **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0